

Cypress Semiconductor Qualification Report

QTP# 97118 VERSION 2.0

July, 2003

**512K x 8 SRAM - R32D Technology - Fab4
CY7C1048/CY7C1049/CY62148**

CYPRESS TECHNICAL CONTACT FOR QUALIFICATION DATA:

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PRODUCT DESCRIPTION (for qualification)			
Information provided in this document is intended for generic qualification and technically describes the Cypress part supplied:			
Marketing Part #:	CY7C1048/CY7C1049/CY62148		
Package:	32-pin, 400-mil SOIC 36-pin, 400-mil SOJ		
Device Description:	512K x 8 Static RAM		
Cypress Division:	Cypress Semiconductor Corporation		
Overall Die (or Mask) REV Level (pre-requisite for qualification):	Rev. A		
What ID markings on Die:	7C1048A/1049A		

TECHNOLOGY/FAB PROCESS DESCRIPTION - R32D			
Number of Metal Layers:	2	Metal Composition:	Metal 1: Al-Cu/TiW Metal 2: TiW/Al-Cu/TiW
Passivation Type and Materials:	Silicon Dioxide 7,000Å + Silicon Nitride 6,000Å		
Number of Transistors in device	26,239,686		
Number of Gates in devices	6,500,000		
Free Phosphorus contents in top glass layer(%):	0%		
Die Coating(s), if used:	N/A		
Generic Process Technology/Design Rule (μ-drawn):	CMOS, Single Local Interconnect, Double Metal /0.5 μm		
Gate Oxide Material/Thickness (MOS):	SiO ₂ / 145Å		
Name/Location of Die Fab (prime) Facility:	Cypress Semiconductor - Bloomington, MN		
Die Fab Line ID/Wafer Process ID:	Fab4/R32D		

PLASTIC PACKAGE/ASSEMBLY DESCRIPTION			
Package Outline, Type, or Name:		32-pin, 400-mil SOIC 36-pin, 400-mil SOJ	
Mold Compound Name/Manufacturer:		NITTO-8000CH	
Lead Frame material:	Copper Alloy 194		
Lead Finish, composition:	Solder Plated, 85%Sn, 15%Pb		
Die Attach Area Plating:	Silver Spot		
Die Attach Method:	Epoxy	Die Attach Material:	Ablestick 8361
Wire Bond Method:	Thermosonic	Wire Material/Size:	Gold / 1.3 mil
JESD22-A112 Moisture Sensitivity Level:	Level 3		
Name/Location of Assembly (prime) facility:	Anam, Korea (SOJ) ASE, Taiwan (SOIC)		

Note: Please contact a Cypress Representative for other packages availability.

RELIABILITY TESTS PERFORMED

Stress/Test	Test Condition (Temp/Bias)	Result P/F
High Temperature Operating Life Latent Failure Rate	Dynamic Operating Condition, Vcc = 5.75V, 150°C	P
Read and Record Life Test	Dynamic Operating Condition, Vcc = 5.75V, 150°C	P
Extended Dynamic Burn-in	Dynamic Operating Condition, Vcc = 5.75V, 150°C	P
Cold Life Test	Dynamic Operating Condition, Vcc=6.5V, -30°C, f=1 MHz	P
High Temperature Steady State Life	Static Operating Condition, Vcc = 5.750V, 150°C	P
High Accelerated Saturation Test (HAST)	140°C, 85%RH, 5.5V Precondition: JESD22 Moisture Sensitivity Level 3 (192 Hrs, 30C/60%RH)	P
Temperature Cycle	MIL-STD-883C, Method 1010, Condition C, -65°C to 150°C Precondition: JESD22 Moisture Sensitivity Level 3 (192 Hrs, 30C/60%RH)	P
High Temp Storage	165°C, no bias	P
Electrostatic Discharge Human Body Model (ESD-HBM)	2,200V MIL-STD-883, Method 3015.7	p
Electrostatic Discharge Charge Device Model (ESD-CDM)	2,000V Cypress Spec. 25-00020	P
Latchup Sensitivity	10.87V In accordance with JEDEC 17. Cypress Spec. 01-00081	P
SEM Analysis	MIL-STD-883, Method 2018	P

RELIABILITY FAILURE RATE SUMMARY

Stress/Test	Device Tested/ Device Hours	# Fails	Activation Energy	Thermal AF ⁴	Failure Rate
High Temperature Operating Life Early Failure Rate ¹	N/A	N/A	N/A	N/A	N/A
High Temperature Operating Life ^{2,3} Long Term Failure Rate	228,320 DHRs	1	0.6	170	26 FIT

¹ Production burn-in of 48hrs/150°C/6.5V is performed for the product.

² Assuming an ambient temperature of 55°C and a junction temperature rise of 15°C.

³ Chi-squared 60% estimations used to calculate the failure rate.

⁴ Thermal Acceleration Factor is calculated from the Arrhenius equation

$$AF = \exp \left[\frac{E_A}{k} \left[\frac{1}{T_2} - \frac{1}{T_1} \right] \right]$$

where:

E_A = The Activation Energy of the defect mechanism.

k = Boltzmann's constant = 8.62×10^{-5} eV/Kelvin.

T_1 is the junction temperature of the device under stress and T_2 is the junction temperature of the device at use conditions.

RELIABILITY TEST DATA
QTP#: 97118

DEVICE	ASSY-LOC	FABLOT#	ASSYLOT#	DURATION	S/S	REJ	FAIL MODE
STRESS: ESD-CHARGE DEVICE MODEL (2,000V)							
CY7C1049-VC	SEOL-L	4714185	619702877/8	COMP	3	0	
STRESS: ESD-HUMAN BODY CIRCUIT PER MIL STD 883, METHOD 3015 (2,200V)							
CY7C1049-VC	SEOL-L	4714185	619702877/8	COMP	3	0	
STRESS: HI-ACCEL SATURATION TEST (140C, 5.5V), PRECOND. 192 HRS 30C/60%RH							
CY7C1049-VC	SEOL-L	4714215	619702951	128	45	0	
CY7C1049-VC	SEOL-L	4714215	619702951	256	44	0	
CY7C1048-SC	TAIWN-G	4716305	619703660	128	48	0	
STRESS: HIGH TEMPERATURE STORAGE (165C, NO BIAS)							
CY7C1049-VC	SEOL-L	4714215	619702951	336	46	0	
CY7C1049-VC	SEOL-L	4714215	619702951	1000	46	0	
STRESS: HIGH TEMP STEADY STATE LIFE TEST (150C, 5.75V)							
CY7C1049-VC	SEOL-L	4714215	619702951	80	76	0	
CY7C1049-VC	SEOL-L	4714215	619702951	168	76	0	
CY7C1048-SC	TAIWN-G	4716305	619703660	80	76	0	
CY7C1048-SC	TAIWN-G	4716305	619703660	168	76	0	
CY7C1048-SC	TAIWN-G	4716305	619703660	256	76	0	
CY7C1049-VC	SEOL-L	4716328	619704042	80	73	0	
CY7C1049-VC	SEOL-L	4716328	619704042	168	77	0	
STRESS: HIGH TEMP DYNAMIC OPERATING LIFE-LATENT FAILURE RATE (150C, 5.75V)							
CY7C1049-VC	SEOL-L	4714215	619702951	80	115	0	
CY7C1049-VC	SEOL-L	4714215	619702951	500	113	0	
CY7C1048-SC	TAIWN-G	4716305	619703660	80	116	0	
CY7C1048-SC	TAIWN-G	4716305	619703660	500	116	1	1 NON VISUAL SINGLE BIT
CY7C1049-VC	SEOL-L	4716328	619704042	80	118	0	
CY7C1049-VC	SEOL-L	4716328	619704042	500	117	0	
STRESS: EXTENDED DYNAMIC BURN-IN (150C, 5.75V)							
CY7C1049-VC	SEOL-L	4714215	619702951	1000	111	0	
STRESS: COLD LIFE TEST (-30C, 6.5V)							
CY7C1049-VC	SEOL-L	4714185	619702877/8	500	45	0	
STRESS: READ & RECORD LIFE TEST (150C, 5.75V)							
CY7C1049-VC	SEOL-L	4714215	619702951	500	10	0	
STRESS: TC COND. C, -65 TO 150C, PRECOND. 192 HRS 30C/60%RH							
CY7C1049-VC	SEOL-L	4714185	619702877/8	300	45	0	
CY7C1049-VC	SEOL-L	4714215	619702951	300	46	0	
CY7C1049-VC	SEOL-L	4714215	619702951	1000	46	0	
CY7C1048-SC	TAIWN-G	4714185	619702975	300	45	0	
CY7C1048-SC	TAIWN-G	4714185	619702975	1000	45	0	
CY7C1049-VC	SEOL-L	4716328	619704042	300	45	0	
CY7C1049-VC	SEOL-L	4716328	619704042	1000	45	0	